P-Channel 18-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)		
- 18	0.0022 at V _{GS} = - 4.5 V	- 95	122 nC		
- 10	0.003 at V _{GS} = - 2.5 V	- 75	122 110		

DFN5X6

PIN1

Top View

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested

APPLICATIONS

Notebook

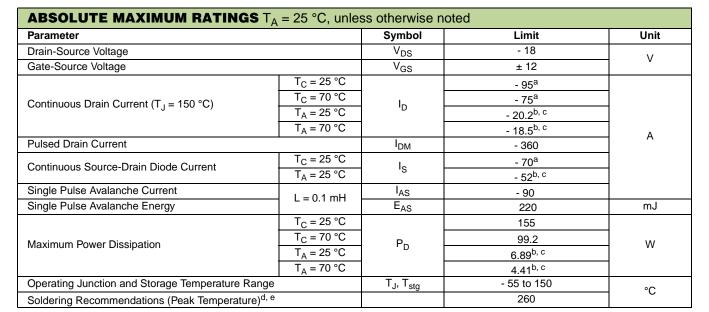
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- Load Switch



THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{b, f}	t ≤ 10 s	R _{thJA}	16	22	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	0.9	1.4	0/10

Notes: a. Package limited.

b. Surface Mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. The DFN5x6 is a leadless package. The end of the lead terminal is exposed

copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

e. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

f. Maximum under Steady State conditions is 54 °C/W.

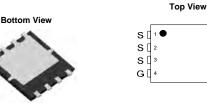
P-Channel MOSFET

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	·						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	- 18			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = - 250 μΑ		- 35		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	iD = - 200 μA		6.5			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 0.5		- 1.2	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA	
Zara Cata Valtaga Drain Current	1	V _{DS} = - 18 V, V _{GS} = 0 V			- 1	-μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 18 V, V _{GS} = 0 V, T _J = 55 °C			- 10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -4.5 V$	- 300			А	
		V _{GS} = - 4.5 V, I _D = - 20 A		0.0022	0.0027	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 15 A		0.003	0.0039		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 5 V, I _D = - 20 A		88		S	
Dynamic ^b				<u>.</u>	.		
Input Capacitance	C _{iss}			15660		pF	
Output Capacitance	C _{oss}	V _{DS} = - 10 V, V _{GS} = 0 V, f = 1 MHz		2135			
Reverse Transfer Capacitance	C _{rss}			992			
Total Gate Charge	Qg			122			
Gate-Source Charge	Q _{gs}	V_{DS} = - 10 V, V_{GS} = - 4.5 V, I_{D} = - 20 A		32		nC	
Gate-Drain Charge	Q _{gd}			39			
Gate Resistance	R _g	f = 1 MHz		1.9		Ω	
Turn-On Delay Time	t _{d(on)}			125			
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		100		ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 20 A, V_GEN = - 4.5 V, R_g = 1 Ω		90			
Fall Time	t _f			50			
Drain-Source Body Diode Characteristic	6						
Continuous Source-Drain Diode Current	ا _S	T _C = 25 °C			95		
Pulse Diode Forward Current ^a	I _{SM}				360	A	
Body Diode Voltage	V _{SD}	I _S = - 5 A		- 0.5	- 1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			53		ns	
Body Diode Reverse Recovery Charge	Q _{rr}			65		nC	
Reverse Recovery Fall Time	t _a	I _F = 3.5 A, dl/dt = 100 A/μs, T _J = 25 °C		26		1	
Reverse Recovery Rise Time	t _b			24		ns	

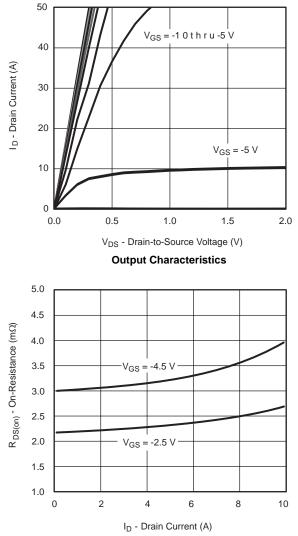
Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

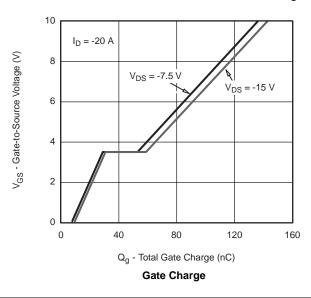
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

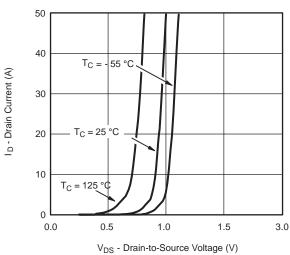




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

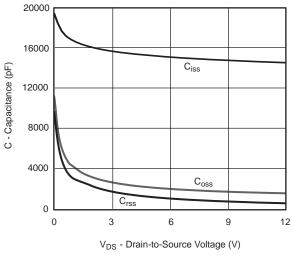




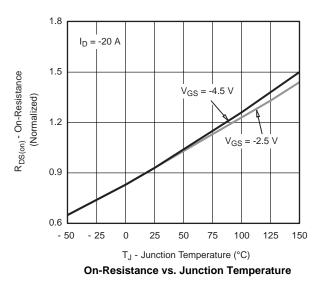


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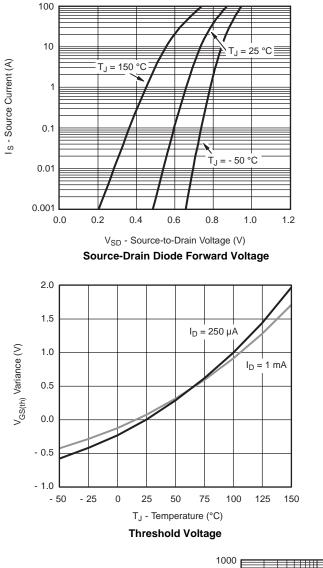
Transfer Characteristics



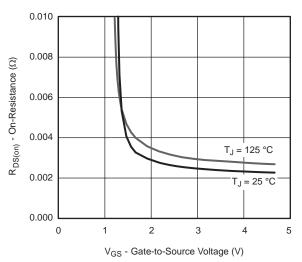




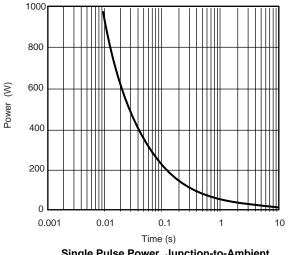


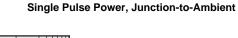


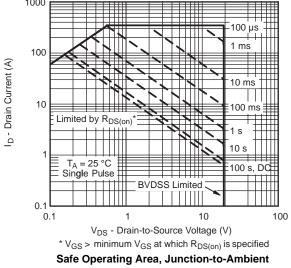
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Gate-to-Source Voltage

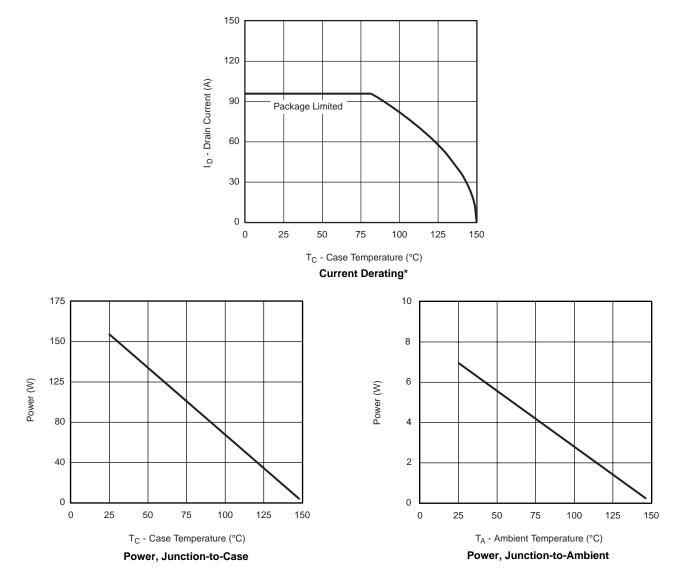








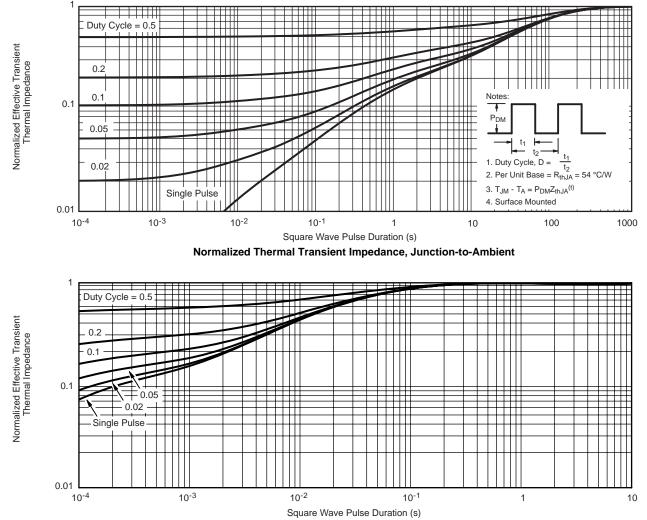
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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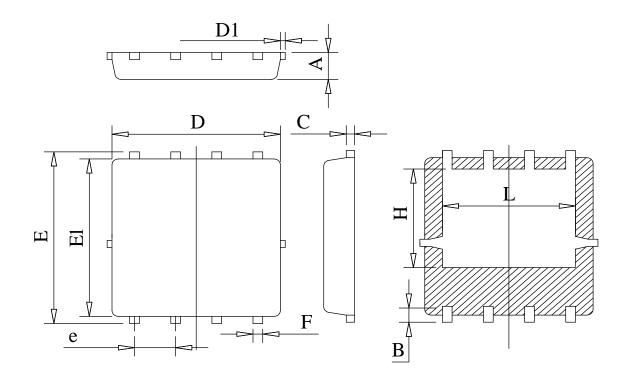


Normalized Thermal Transient Impedance, Junction-to-Case



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DFN5X6-8L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Unit : mm			
Symbol	Min	Тур	Max
А	0.78	0.95	1.12
В	0.45	0.58	0.78
С	0.18	0.254	0.36
D	4.70	5.20	5.45
D1			0.18
Е	5.85	6.05	6.25
E1	5.38	5.55	5.98
e	1.15	1.27	1.40
F	0.18	0.30	0.52
Н	3.25	3.47	3.70
L	3.75	4.00	4.25



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